NSN 5961-01-222-9037

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Inclosure Material:
Metal
Overall Length:
1.510 inches
End Application:
1430-01-181-5884
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.855 inches and 0.875 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-6.0 breakdown voltage, collector-to-base, emitter open and -100.0 collector to emitter voltage/static/base open
Current Rating Per Characteristic:
Between -5.00 amperes source cutoff current and -20.00 amperes source cutoff current
Power Rating Per Characteristic:
125.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
18876-11437748 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 wire hook
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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